

Spezifikationen	
Artikelnummer	PSMN3R5-25MLDX
Hersteller	Nexperia
Beschreibung	PSMN3R5-25MLD/MLFPAK/REEL 7 Q
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2669 pcs Stock
VGS (th) (Max) @ Id	2.2V @ 1mA
Vgs (Max)	±20V
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	LFPAK56, Power-SO8
Serie	-
Rds On (Max) @ Id, Vgs	6.4 mOhm @ 25A, 10V
Verlustleistung (max)	65W (Tc)
Verpackung	Original-Reel®
Verpackung / Gehäuse	SC-100, SOT-669
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	1334pF @ 12V
Gate Charge (Qg) (Max) @ Vgs	18.9nC @ 10V
Typ FET	N-Channel
FET-Merkmal	Schottky Diode (Body)
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	70A

sein:

PSMN3R4-30PL MOS
NXP
NXP TO-220



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YIC International Co., Limited.

PSMN3R5-30YL
NXP
PSMN3R5-30YL NXP



PSMN3R5-30LL
NXP
PSMN3R5-30LL NXP



PSMN3R5-30LL,115
NXP USA Inc.
MOSFET N-CH 30V QFN3333



PSMN3R4-30PL,127
Nexperia USA Inc.
MOSFET N-CH 30V TO220AB



PSMN3R4-30BLE,118
Nexperia USA Inc.
MOSFET N-CH 30V D2PAK



PSMN3R5-30YL,115
Nexperia USA Inc.
MOSFET N-CH 30V 100A LPAK

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PSMN3R4-30PL
NXP
PSMN3R4-30PL NXP

Mehr

Schlusswort	Nexperia PSMN3R5-25MLDX	PSMN3R5-25MLDX-Datenblatt	PSMN3R5-25MLDX-Datenblätter	PSMN3R5-25MLDX PDF	Nexperia PSMN3R5-25MLDX
PSMN3R5-25MLDX Electronic	PSMN3R5-25MLDX Electronic	PSMN3R5-25MLDX-Komponenten	PSMN3R5-25MLDX-Verteiler	PSMN3R5-25MLDX-Bild	PSMN3R5-25MLDX-Teil
PSMN3R5-25MLDX Preis	PSMN3R5-25MLDX Hersteller	PSMN3R5-25MLDX Bild	PSMN3R5-25MLDX Aktie	PSMN3R5-25MLDX Inventar	PSMN3R5-25MLDX Preis
PSMN3R5-25MLDX Neu	PSMN3R5-25MLDX Original	PSMN3R5-25MLDX garantiert	PSMN3R5-25MLDX RFQ	PSMN3R5-25MLDX Online bestellen	PSMN3R5-25MLDX Neu